

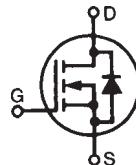
# PolarHV™ HiPerFET Power MOSFET

Electrically Isolated Tab

IXFR 44N80P

$V_{DSS}$	=	800	V
$I_{D25}$	=	25	A
$R_{DS(on)}$	$\leq$	200	$m\Omega$
$t_{rr}$	$\leq$	250	ns

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

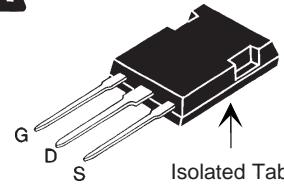


Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ C$ to $150^\circ C$	800	V	
$V_{DGR}$	$T_J = 25^\circ C$ to $150^\circ C$ ; $R_{GS} = 1 M\Omega$	800	V	
$V_{GS}$	Continuous	$\pm 30$	V	
$V_{GSM}$	Transient	$\pm 40$	V	
$I_{D25}$	$T_c = 25^\circ C$	25	A	
$I_{DM}$	$T_c = 25^\circ C$ , pulse width limited by $T_{JM}$	100	A	
$I_{AR}$	$T_c = 25^\circ C$	25	A	
$E_{AR}$	$T_c = 25^\circ C$	80	$mJ$	
$E_{AS}$	$T_c = 25^\circ C$	3.4	J	
$dv/dt$	$I_s \leq I_{DM}$ , $di/dt \leq 100 A/\mu s$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ , $R_G = 10 \Omega$	10	V/ns	
$P_D$	$T_c = 25^\circ C$	300	W	
$T_J$		-55 ... +150	$^\circ C$	
$T_{JM}$		150	$^\circ C$	
$T_{stg}$		-55 ... +150	$^\circ C$	
$T_L$	1.6 mm (0.062 in.) from case for 10 s	300	$^\circ C$	
$T_{SOLD}$	Plastic body for 10 seconds	260	$^\circ C$	
$V_{ISOL}$	50/60 Hz, RMS, 1 minute	2500	V~	
$F_c$	Mounting force	20..120 / 4.5..25	N/lb	
Weight		5	g	

Symbol	Test Conditions ( $T_J = 25^\circ C$ unless otherwise specified)	Characteristic Values		
		Min.	Typ.	Max.
$BV_{DSS}$	$V_{GS} = 0 V$ , $I_D = 800 \mu A$	800		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 8 mA$	3.0		V
$I_{GSS}$	$V_{GS} = \pm 30 V$ , $V_{DS} = 0 V$		$\pm 200$	nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$		50	$\mu A$
			1.5	mA
$R_{DS(on)}$	$V_{GS} = 10 V$ , $I_D = I_T$ , Note 1		200	$m\Omega$

ISOPLUS247 (IXFR)

E153432



G = Gate      D = Drain  
S = Source

## Features

- Silicon chip on Direct-Copper-Bond substrate
  - High power dissipation
  - Isolated mounting surface
  - 2500V electrical isolation
- Low drain to tab capacitance(<30pF)
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Fast intrinsic Rectifier

## Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control

## Advantages

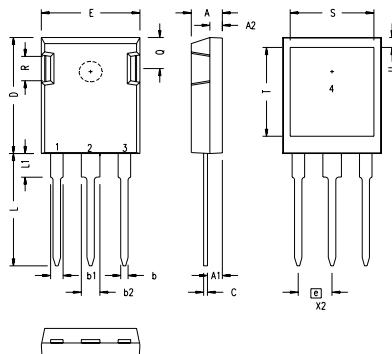
- Easy assembly
- Space savings
- High power density

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ unless otherwise specified)	Min.	Typ.
$g_{fs}$	$V_{DS} = 20 \text{ V}; I_D = I_T$ , Note 1	27	43	S
$C_{iss}$			12	nF
$C_{oss}$	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	910		pF
$C_{rss}$		30		pF
$t_{d(on)}$		28		ns
$t_r$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_D = 44 \text{ A}$	22		ns
$t_{d(off)}$	$R_G = 1 \Omega$ (External)	75		ns
$t_f$		27		ns
$Q_{g(on)}$		200		nC
$Q_{gs}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_D = I_T$	67		nC
$Q_{gd}$		65		nC
$R_{thJC}$			0.42	°C/W
$R_{thCS}$		0.15		°C/W

**Source-Drain Diode****Characteristic Values** $T_J = 25^\circ\text{C}$  unless otherwise specified)

Symbol	Test Conditions	Min.	Typ.	Max.
$I_s$	$V_{GS} = 0 \text{ V}$		44	A
$I_{SM}$	Repetitive		100	A
$V_{SD}$	$I_F = I_S, V_{GS} = 0 \text{ V}$ , Note 1		1.5	V
$t_{rr}$	$I_F = 22 \text{ A}, -di/dt = 100 \text{ A}/\mu\text{s}$		250	ns
$Q_{RM}$	$V_R = 100 \text{ V}, V_{GS} = 0 \text{ V}$	0.8		μC
$I_{RM}$		8.0		A

Notes: 1. Pulse test,  $t \leq 300 \mu\text{s}$ , duty cycle  $d \leq 2\%$ ;  
 2. Test current  $I_T = 22 \text{ A}$ .

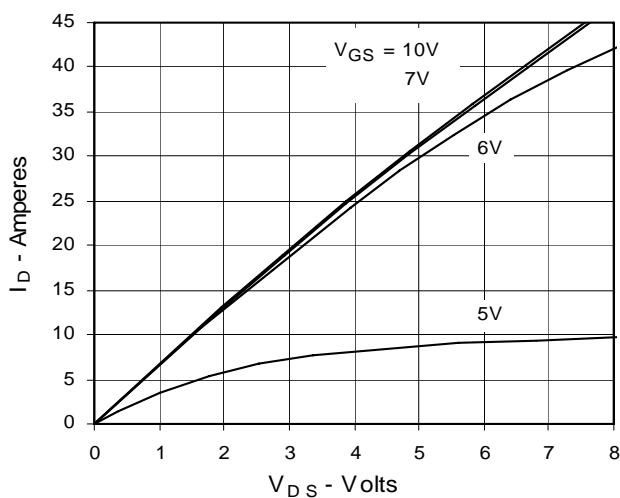
**ISOPLUS247 (IXFR) Outline**

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b1	.075	.084	1.91	2.13
b2	.115	.123	2.92	3.12
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
E	.620	.635	15.75	16.13
e	.215 BSC		5.45 BSC	
L	.780	.800	19.81	20.32
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.520	.540	13.21	13.72
T	.620	.640	15.75	16.26
U	.065	.080	1.65	2.03

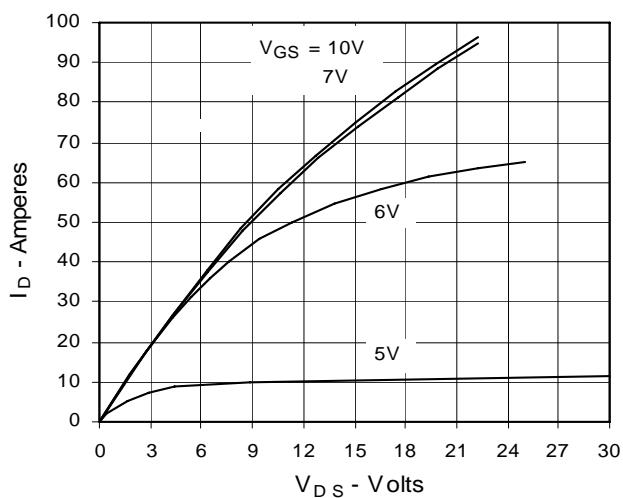
1 – GATE  
 2 – DRAIN (COLLECTOR)  
 3 – SOURCE (EMITTER)  
 4 – NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.

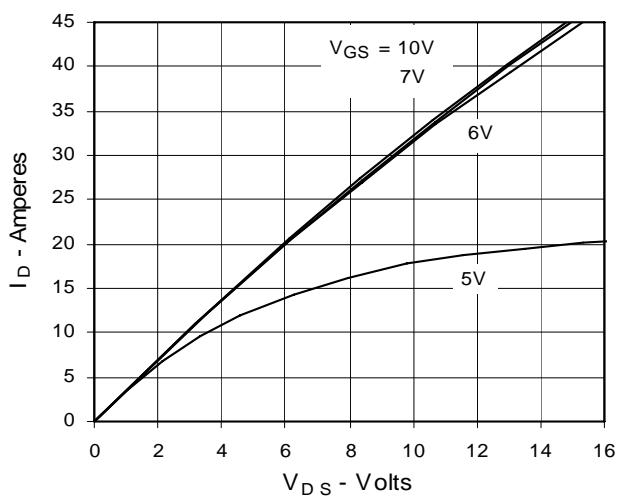
**Fig. 1. Output Characteristics  
@ 25°C**



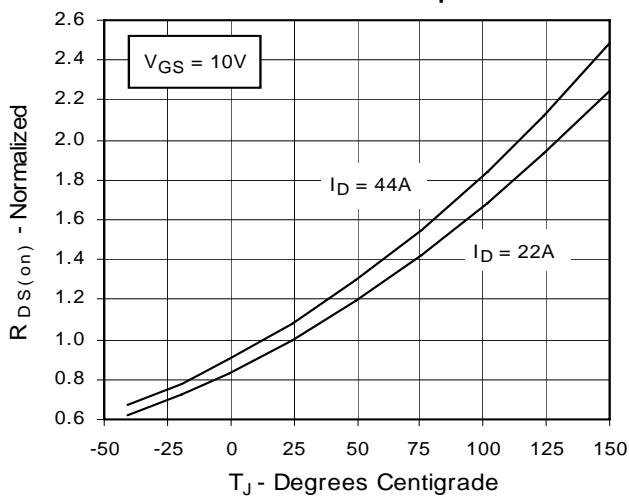
**Fig. 2. Extended Output Characteristics  
@ 25°C**



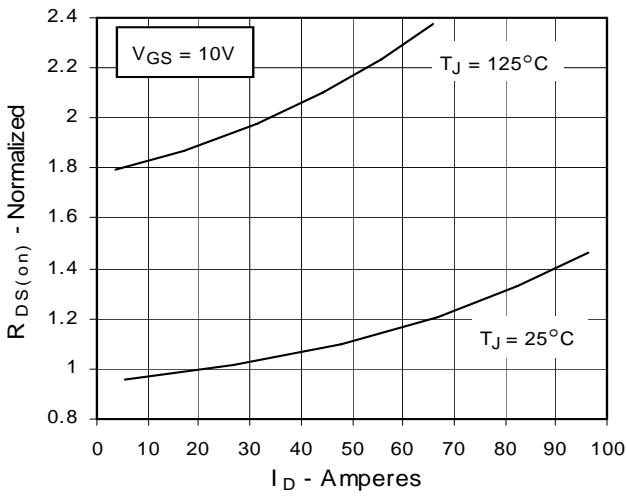
**Fig. 3. Output Characteristics  
@ 125°C**



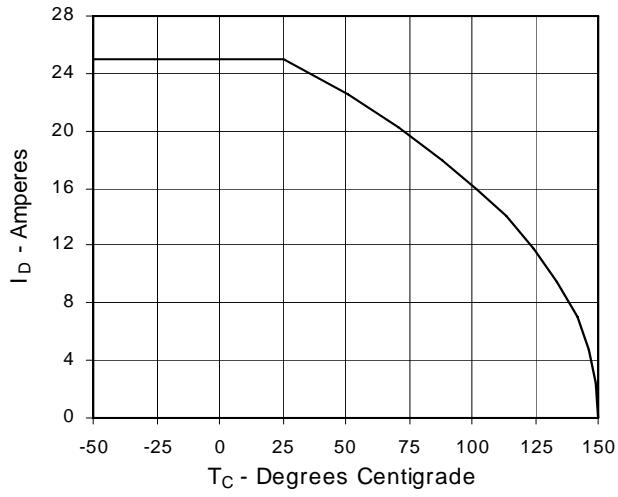
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 22A$   
Value vs. Junction Temperature**

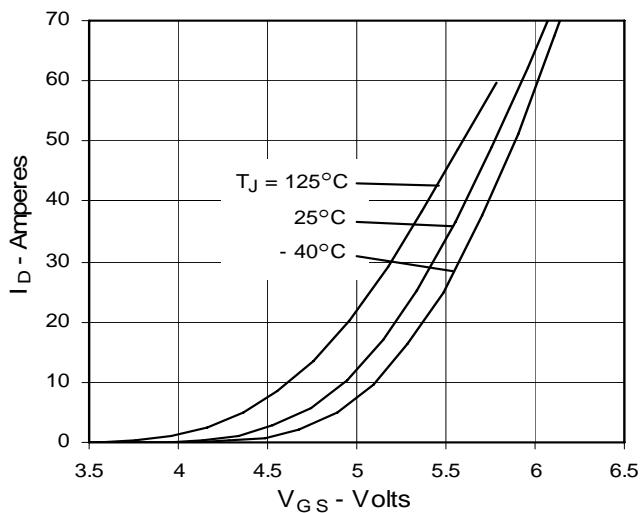
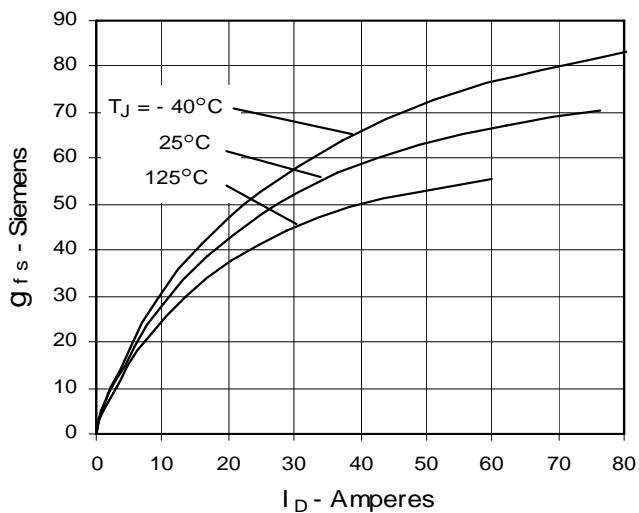
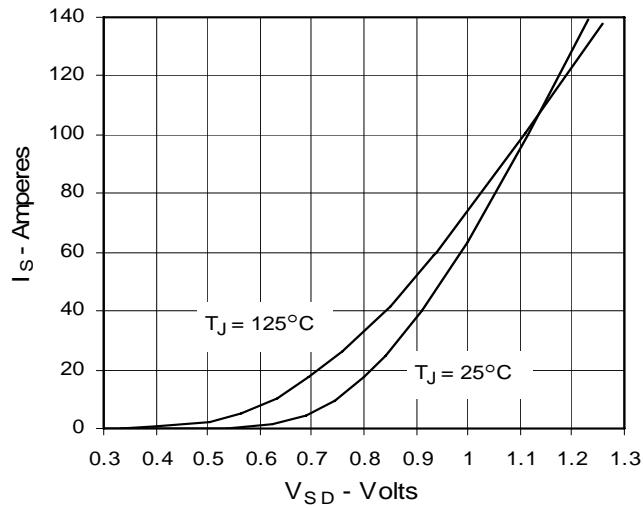
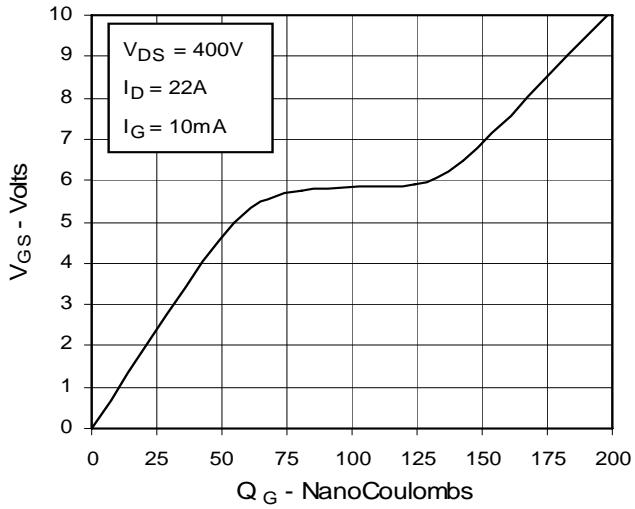
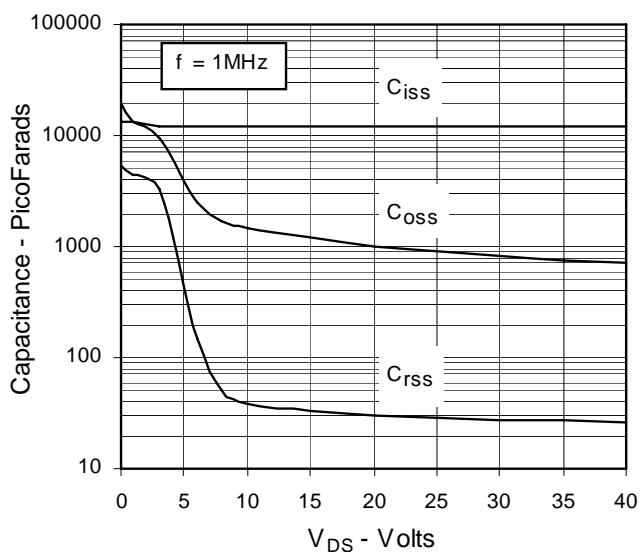
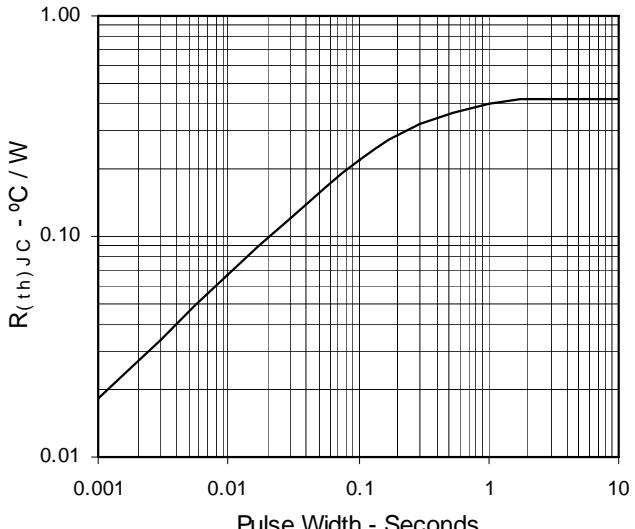


**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 22A$   
Value vs. Drain Current**



**Fig. 6. Drain Current vs. Case  
Temperature**



**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Source Current vs. Source-To-Drain Voltage****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 12. Maximum Transient Thermal Resistance**



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